

line, a source electrode connected to the data line, a drain electrode which is separated from the drain electrode and opposite to the drain electrode with the respect to the gate electrode, and a data pad which is connected to the data line and receives a signal from a external circuit.

50. (Original) The thin film transistor array panel of claim 45, wherein the inter-layer reaction layer includes silicon or transition metal.

### ***Conclusion***

It is respectfully requested that this amendment be entered prior to the examination of the above-referenced patent application. By this amendment, claims 10-15 and 45-50 are now pending, of which claims 10 and 45 are independent claims. It is believed that no new matter is added by this amendment. If the Examiner desires any additional information, the Examiner is invited to contact Applicants' attorney at the telephone number listed below to expedite prosecution.

Prompt and favorable consideration is respectfully requested.

Respectfully submitted,



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